



	<p>IRFBE30L</p>
	<p>Manufacturer Part Number: IRFBE30L</p> <p>Manufacturer/Brand: Electro-Films (EFI) / Vishay</p> <p>Part of Description: MOSFET N-CH 800V 4.1A TO-262</p> <p>Datasheets:  IRFBE30L.pdf</p> <p>RoHs Status: Contains lead / RoHS non-compliant</p> <p>Stock Condition: New original, 1000 pcs Stock Available.</p> <p>Ship From: Hong Kong</p> <p>Shipment Way: DHL/Fedex/TNT/UPS/EMS</p>
	
<p>Image may be representation. See specs for product details.</p>	

Specifications

Part Number	IRFBE30L
Manufacturer	Electro-Films (EFI) / Vishay
Description	MOSFET N-CH 800V 4.1A TO-262
Category	Discrete Semiconductor Products > Transistors - FETs,
Part Status	1000 pcs Stock
Detailed Description	N-Channel 800V 4.1A (Tc) 125W (Tc) Through Hole
Series	-
Technology	MOSFET (Metal Oxide)
Operating Temperature	-55°C ~ 150°C (TJ)
Mounting Type	Through Hole
Package / Case	TO-262-3 Long Leads, IPak, TO-262AA
Supplier Device Package	I2PAK
Power Dissipation (Max)	125W (Tc)
FET Type	N-Channel
FET Feature	-
Drain to Source Voltage (Vdss)	800V
Current - Continuous Drain (Id) @ 25°C	4.1A (Tc)
Rds On (Max) @ Id, Vgs	3 Ohm @ 2.5A, 10V
Vgs(th) (Max) @ Id	4V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	78nC @ 10V
Input Capacitance (Ciss) (Max) @ Vds	1300pF @ 25V
Drive Voltage (Max Rds On, Min Rds On)	10V
Vgs (Max)	±20V
Packaging	Tube
Lead Free Status / RoHS Status	Contains lead / RoHS non-compliant
Moisture Sensitivity Level (MSL)	1 (Unlimited)
Other Names	*IRFBE30L

IRFBE30L is New Original in Stock, Search IRFBE30L Datasheets, PDF, Inventory at Y-IC.com Online, Order IRFBE30L Electro-Films (EFI) / Vishay with warrantied and confidence.
RFQ IRFBE30L : Info@Y-IC.com

You May Be Also Be interested In:

 <p>IRFBE30LPBF-M IR IRFBE30LPBF-M IR</p>	 <p>IRFBE30PBF Vishay / Siliconix MOSFET N-CH 800V 4.1A TO-220AB</p>	 <p>IRFBE20STRR Vishay / Siliconix MOSFET N-CH 800V 1.8A D2PAK</p>	 <p>IRFBE30LPBF Electro-Films (EFI) / Vishay MOSFET N-CH 800V 4.1A TO-262</p>
 <p>IRFBE30PBF Electro-Films (EFI) / Vishay MOSFET N-CH 800V 4.1A TO-220AB</p>	 <p>IRFBE30LPBF Vishay / Siliconix MOSFET N-CH 800V 4.1A TO-262</p>	 <p>IRFBE30L Vishay / Siliconix MOSFET N-CH 800V 4.1A TO-262</p>	 <p>IRFBE30 Electro-Films (EFI) / Vishay MOSFET N-CH 800V 4.1A TO-220AB</p>

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 IRFBC40LPBF	 IRFBC40S	 IRFBC40S	 IRFBC40SPBF	 IRFBC40SPBF
 IRFBC40STRL	 IRFBC40STRL	 IRFBC40STRLPBF	 IRFBC40STRLPBF	 IRFBC40STRR
 IRFBC40STRR	 IRFBC41LC	 IRFBE20PBF	 IRFBE20PBF	 IRFBE20SPBF
 IRFBE30L	 IRFBE30LPBF-M	 IRFBE30PBF	 IRFBE30PBF	 IRFBE30SPBF
 IRFBE30SPBF	 IRFBE30STRLPBF	 IRFBE30STRLPBF	 IRFBE30STRLPBF	 IRFBE30STRLPBF
 IRFBE30STRL	 IRFBE30STRL	 IRFBE30STRLPBF	 IRFBE30STRLPBF	 IRFBE30STRLPBF
 IRFBG20PBF	 IRFBG30PBF	 IRFBG30PBF	 IRFBL10N60A	 IRFC480LCD
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